### TOSHIBA DIODE SILICON EPITAXIAL SCHOTTKY BARRIER TYPE

# 155384

#### LOW VOLTAGE HIGH SPEED SWITCHING

- Small Package
- Composed of 2 independent diodes.
- Low Forward Voltage:  $V_{F(2)} = 0.23V$  (TYP.) @I<sub>F</sub>=5mA

### MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Maximum (Peak) Reverse Voltage	$v_{ m RM}$	15	V
Reverse Voltage	$v_{ m R}$	10	V
Maximum (Peak) Forward Current	$I_{ extbf{FM}}$	200 ※	mA
Average Forward Current	$I_{O}$	100 ※	mA
Surge Current (10ms)	$I_{ ext{FSM}}$	1	Α
Power Dissipation	P	100 ※	mW
Junction Temperature	$\mathrm{T_{j}}$	125	°C
Storage Temperature Range	${ m T_{stg}}$	-55~125	°C
Operating Temperature Range	$T_{ m opr}$	-40~100	°C

1. ANODE 1
2. ANODE 2
3. CATHODE 2
4. CATHODE 1
JEDEC
EIAJ
TOSHIBA
1-2U1A

Weight: 0.006g

※ Unit Rating. Total Rating=Unit Rating × 1.5

#### ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT		
Forward Voltage	V <sub>F (1)</sub>	I <sub>F</sub> =1mA	_	0.18	_	V		
	$V_{F(2)}$	$I_{\mathbf{F}} = 5 \text{mA}$	_	0.23	0.30	V		
	V <sub>F (3)</sub>	$I_{ m F} = 100 { m mA}$		0.35	0.50	V		
Reverse Current	$I_{\mathbf{R}}$	$V_R = 10V$	_	_	20	$\mu$ <b>A</b>		
Total Capacitance	$\mathrm{C}_{\mathrm{T}}$	$V_R=0$ , f=1MHz	_	20	40	pF		

### PIN ASSIGNMENT (TOP VIEW)

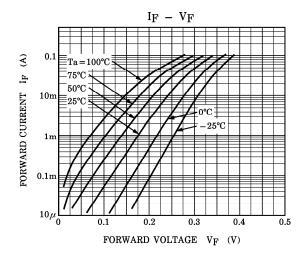


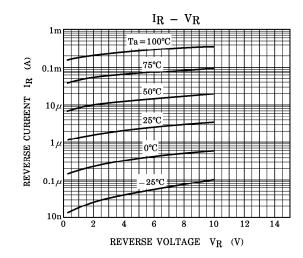
## MARKING

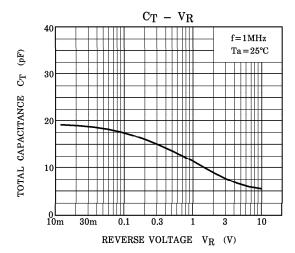


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